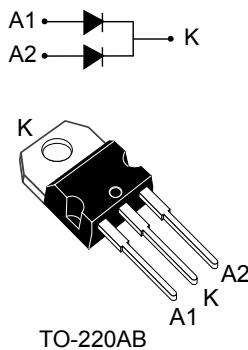


100 V power Schottky rectifier



Features

- High junction temperature capability
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche capability
- ECOPACK®2 compliant

Applications

- Switching diode
- SMPS
- DC/DC converter
- Telecom power
- Desktop power supply

Description

This dual diode common cathode Schottky rectifier is suited for high frequency switched mode power supplies.

Packaged in TO-220AB, the **STPS60H100C** is optimized for use to enhance the reliability of the application.

Product status	
STPS60H100C	
Product summary	
$I_{F(AV)}$	2 x 30 A
V_{RRM}	100 V
$T_j(\text{max.})$	175 °C
$V_F(\text{typ.})$	0.67 V

1 Characteristics

Table 1. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	100	V
$I_{F(RMS)}$	Forward rms current	60	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$, square wave	$T_c = 150$ °C	Per diode
		$T_c = 140$ °C	Per device
I_{FSM}	Surge non repetitive forward current	$t_p = 10$ ms sinusoidal	300
P_{ARM}	Repetitive peak avalanche power	$t_p = 10$ μ s, $T_j = 125$ °C	1300
T_{stg}	Storage temperature range	-65 to +175	
T_j	Maximum operating junction temperature ⁽¹⁾	+175	°C

1. $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter	Max. value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	1.0
		Total	0.7
$R_{th(c)}$	Coupling	0.4	°C/W

When the diodes 1 and 2 are used simultaneously: ΔT_j (diode1) = $P_{(diode1)} \times R_{th(j-c)}$ (per diode) + $P_{(diode2)} \times R_{th(c)}$

For more information, please refer to the following application note :

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I_R ⁽¹⁾	Reverse leakage current	$T_j = 25$ °C	$V_R = V_{RRM}$	-	2	10	µA
		$T_j = 125$ °C		-	3	10	mA
V_F ⁽²⁾	Forward voltage drop	$T_j = 25$ °C	$I_F = 30$ A	-		0.84	V
		$T_j = 125$ °C		-	0.67	0.72	
		$T_j = 25$ °C	$I_F = 60$ A	-		0.98	
		$T_j = 125$ °C		-	0.80	0.84	

1. Pulse test: $t_p = 5$ ms, $\delta < 2\%$

2. Pulse test: $t_p = 380$ μ s, $\delta < 2\%$

To evaluate the conduction losses, use the following equation: $P = 0.6 \times I_{F(AV)} + 0.004 \times I_F^2$ (RMS)

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (per diode)

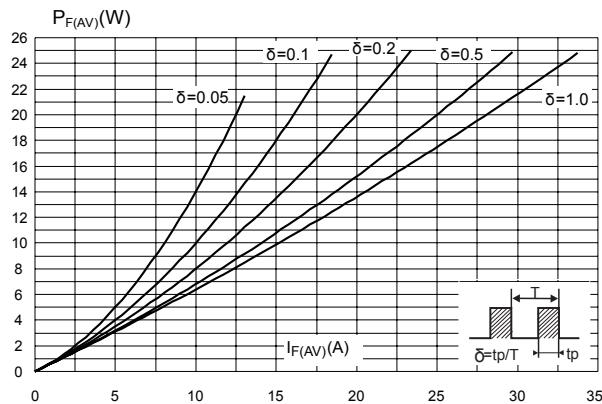


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

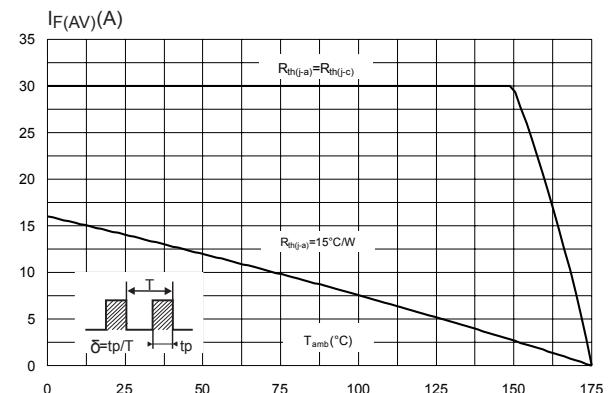


Figure 3. Normalized avalanche power derating versus pulse duration ($T_j = 125$ °C)

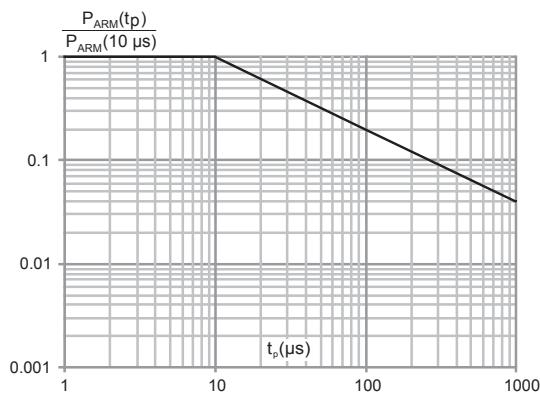


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

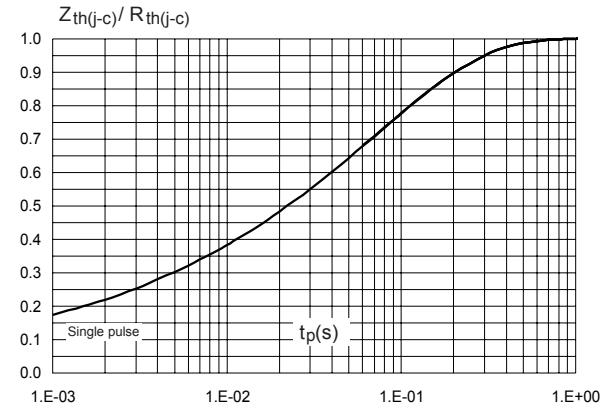


Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

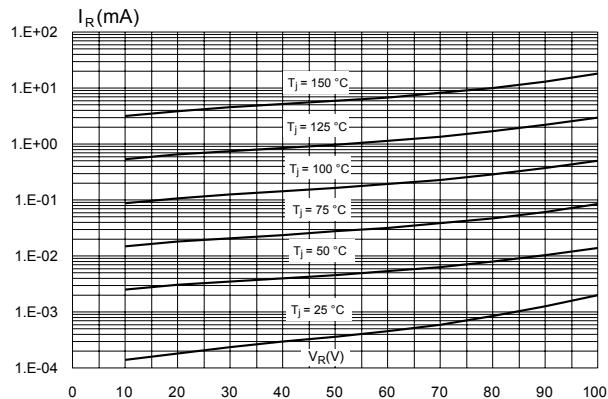


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

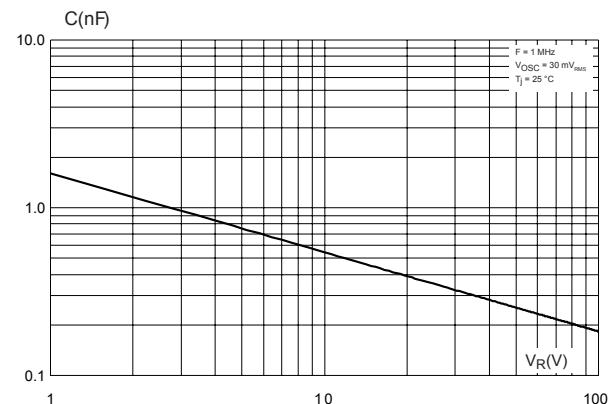
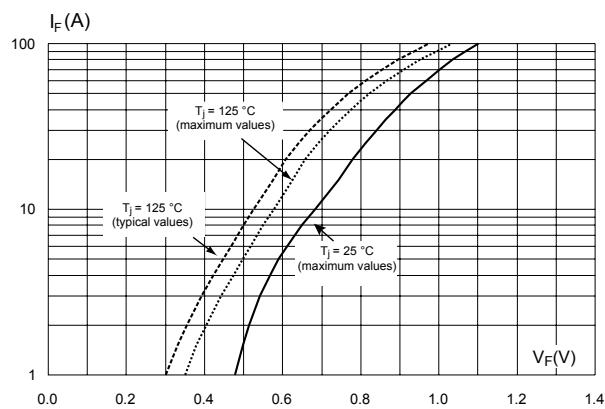


Figure 7. Forward voltage drop versus forward current (per diode)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TO-220AB package information

- Epoxy meets UL 94,VO
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 8. TO-220AB package outline

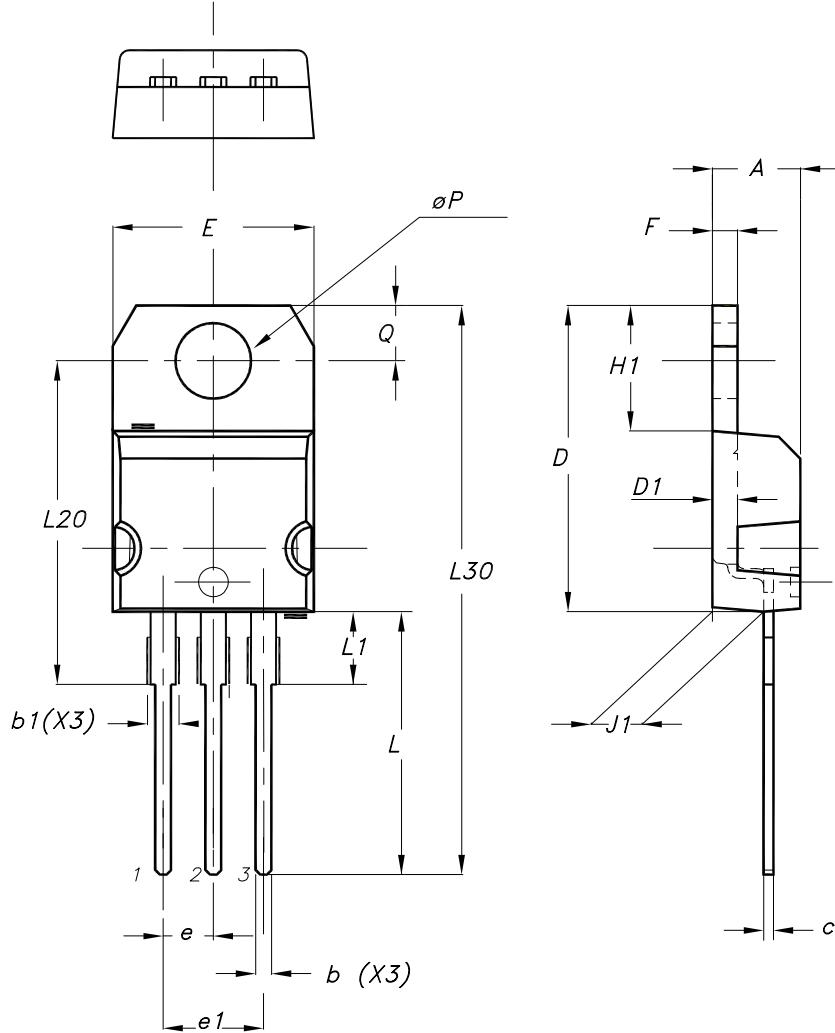


Table 4. TO-220AB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
b	0.61	0.88	0.240	0.035
b1	1.14	1.55	0.045	0.061
c	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
D1	1.27 typ.		0.050 typ.	
E	10.00	10.40	0.394	0.409
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.244	0.260
J1	2.40	2.72	0.094	0.107
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.40 typ.		0.646 typ.	
L30	28.90 typ.		1.138 typ.	
θP	3.75	3.85	0.148	0.152
Q	2.65	2.95	0.104	0.116

3 Ordering information

Table 5. Order code

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS60H100CT	STPS60H100CT	TO-220AB	1.95 g	50	Tube

Revision history

Table 6. Document revision history

Date	Revision	Changes
02-Aug-2004	1	First issue.
07-Feb-2007	2	Reformatted to current standards. Added ECOPACK statement on page 5. Corrected typographical errors on pages 1 and 3.
09-Aug-2018	3	Updated Table 1. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus pulse duration (T_j= 125 °C) .

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